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Docket: 740756-1838

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of)
Shunpei YAMAZAKI et al.)
Serial No. 09/118,010) Art Unit: 2822
Filed: July 17, 1998) Examiner: M. Guerrero
For: SEMICONDUCTOR DEVICE, METHOD)
OF FABRICATING SAME, AND)

PRELIMINARY AMENDMENT

Honorable Commissioner for Patents and Trademarks

ELECTROOPTICAL DEVICE

Washington, D.C. 20231

RECEIVED

) Date: February 14, 2002

FEB 1 4 2002

Sir:

OFFICE OF PETITIONS

Please preliminarily amend the subject application as follows:

IN THE CLAIMS:

Please add new claims 47-73 as follows:

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--47. A semiconductor device comprising:

a resinous substrate having an uneven surface;

a resinous layer provided on said uneven surface of said resinous substrate and having a planarized surface; and

a thin-film transistor provided on said planarized surface of said resinous layer;

an interlayer insulating layer comprising a resinous material provided over said thin-film transistor; and

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